

Precision, Wide Bandwidth Quad SPDT Analog Switch

Product Features

- Single Supply Operation (+2V to +6V)
- Rail-to-Rail Analog Signal Dynamic Range
- Low On-Resistance (6 Ohm typ with 5V supply)
Minimizes Distortion and Error Voltages
- On-Resistance Matching Between Channels, 0.4 Ohm Typ.
- On-Resistance Flatness, <2 Ohm Typ.
- Low Charge Injection Reduces Glitch Errors, Q = 6pC Typ.
- Replaces Mechanical Relays
- High Speed. t_{ON} , 8ns Typ.
- Low Crosstalk: -100dB @ 10 MHz
- Low Off-Isolation: -57dB @ 10 MHz
- Wide -3dB Bandwidth: 230 MHz
- High-Current Channel Capability: >100mA
- TTL/CMOS Logic Compatible
- Low Power Consumption (0.5 μ W typ.)
- Packaging: 16-pin QSOP (Q16), and 16-pin SOIC (W16)

Applications

- Audio, Video Switching and Routing
- LAN Switches
- Telecommunication Systems
- Battery-Powered Systems

Description

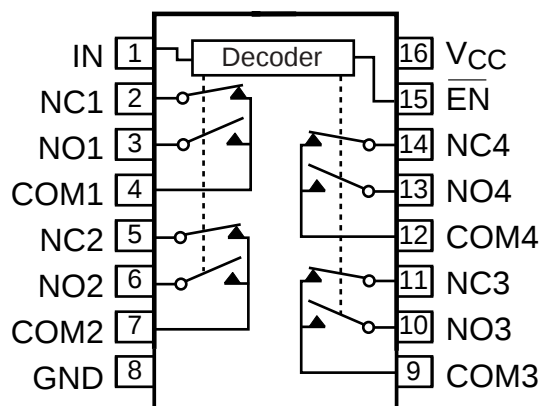
The PI5A100 is an improved Quad Single-pole double-throw (4SPDT) CMOS analog switch designed to operate with a single +2V to +6V power supply. The EN pin may be used to place all switches in a high-impedance state. This high precision device is ideal for low-distortion audio, video, and data switching and routing.

Each switch conducts current equally well in either direction when on. In the off state each switch blocks voltages up to the power-supply rails.

The PI5A100 is fully specified with +5V, and +3.3V supplies. With +5V, it guarantees less than 10 Ohm On-resistance. On-resistance matching between channels is within 2 Ohm. On-resistance flatness is less than 4 Ohm over the specified range. The PI5A100 guarantees fast switching speeds ($t_{ON} < 12ns$).

The PI5A100 is available in the narrow-body SOIC-16, and QSOP-16 packages for operation over the industrial (-40°C to +85°C) temperature range.

Functional Block Diagram, Pin Configuration and Truth Table



$\overline{EN}$	IN	ON Switch
0	0	NC1, NC2, NC3, NC4
0	1	NO1, NO2, NO3, NO4
1	X	None. Disabled

Switches shown for logic "0" input.

NC = Normally Closed; NO = Normally Open

Absolute Maximum Ratings

Voltages Referenced to Gnd

V_{CC} -0.5V to +7V

V_{IN} , V_{COM} , V_{NC} , V_{NO} (Note 1) -0.5V to $V_{CC}+2V$

..... or 30mA, whichever occurs first

Current (any terminal except COM, NO, NC) 30mA

Current, COM, NO, NC

(pulsed at 1ms, 10% duty cycle) 120mA

Thermal Information

Continuous Power Dissipation

Narrow SO & QSOP

(derate 8.7mW/°C above +70°C) 650mW

Storage Temperature -65°C to +150°C

Lead Temperature (soldering, 10s) +300°C

Note 1:

Signals on NC, NO, COM, or IN exceeding V_{CC} or Gnd are clamped by internal diodes. Limit forward diode current to 30mA.

Caution: Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.

Electrical Specifications - Single +5V Supply

($V_{CC} = +5V \pm 10\%$, GND = 0V, $V_{INH} = 2.4V$, $V_{INL} = 0.8V$)

Parameter	Symbol	Conditions	Temp (°C)	Min ⁽¹⁾	Typ ⁽²⁾	Max ⁽¹⁾	Units
Analog Switch							
Analog Switch Range ⁽³⁾	V_{ANALOG}		Full	0		V_{CC}	V
On-Resistance	R_{ON}	$V_{CC} = 4.5V$, $I_{COM} = -30mA$, V_{NO} or $V_{NC} = +2.5V$	25		8	10	Ω
			Full			12	
On-Resistance Match Between Channels ⁽⁶⁾	ΔR_{ON}		25		0.8	2	
			Full			4	
On-Resistance Flatness ⁽⁵⁾	$R_{FLAT(ON)}$	$V_{CC} = 5V$, $I_{COM} = -30mA$, V_{NO} or $V_{NC} = 1V, 2.5V, 4V$	25		2	3	nA
			Full			4	
NO or NC Off Leakage Current ⁽⁶⁾	$I_{NO(OFF)}$ or $I_{NC(OFF)}$	$V_{CC} = 5.5V$, $I_{COM} = 0V$, V_{NO} or $V_{NC} = 4.5V$	25		0.07		
			Full	-80		80	
COM Off Leakage Current ⁽⁶⁾	$I_{COM(OFF)}$	$V+ = 5.5V$, $I_{COM} = +4.5V$, V_{NO} or $V_{NC} = \pm 4.5V$	25		0.01		
			Full	-80		80	
COM On Leakage Current ⁽⁶⁾	$I_{COM(ON)}$	$V+ = 5.5V$, $I_{COM} = +4.5V$, V_{NO} or $V_{NC} = +4.5V$	25		0.016		nA
			Full	-80		80	

continued

Electrical Specifications - Single +5V Supply (continued)

 $(V_{CC} = +5V \pm 10\%, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V)$

Parameter	Symbol	Conditions	Temp (°C)	Min ⁽¹⁾	Typ ⁽²⁾	Max ⁽¹⁾	Units
Logic Input							
Input High Voltage	V _{IH}	Guaranteed logic High Level	Full	2			V
Input Low Voltage	V _{IL}	Guaranteed logic Low Level				0.8	
Input Current with Input Voltage High	I _{INH}	V _{IN} = 2.4V, all others = 0.8V	Full	-1	0.005	1	μA
Input Current with Input Voltage Low	I _{INL}	V _{IN} = 0.8V, all others = 2.4V		-1	0.005	1	
Dynamic							
Turn-On Time	t _{ON}	V _{CC} = 5V, Figure 1	25		8	15	ns
			Full			20	
Turn-Off Time	t _{OFF}		25		3.5	7	
			Full			10	
Charge Injection ⁽³⁾	Q	C _L =1nF, V _{GEN} = 0V, R _{GEN} = 0 ohm, Figure 2	25			10	pC
Off Isolation	OIRR	R _L = 50 ohm, C _L = 5pF, f = 10MHz, Figure 3			-57		dB
Crosstalk ⁽⁸⁾	X _{TALK}	R _L = 50 ohm, C _L = 5pF, f = 10MHz, Figure 4			-100		
NC or NO Capacitance	C _(OFF)	f=1kHz, Figure5			8		pF
COM Off Capacitance	C _{COM(OFF)}				14		
COM On Capacitance	C _{COM(ON)}	f=1kHz, Figure 6			18		
-3dB Bandwidth	BW	R _L = 50 ohm, Figure 7	Full		230		MHz
Distortion	D	R _L = 10k-ohm,			0.2		%
Supply							
Power-Supply Range	V _{CC}		Full	2		6	V
Positive Supply Current	I _{CC}	V _{CC} = 5.5V, V _{IN} = 0V or V _{CC} , all channels on or off				1	μA

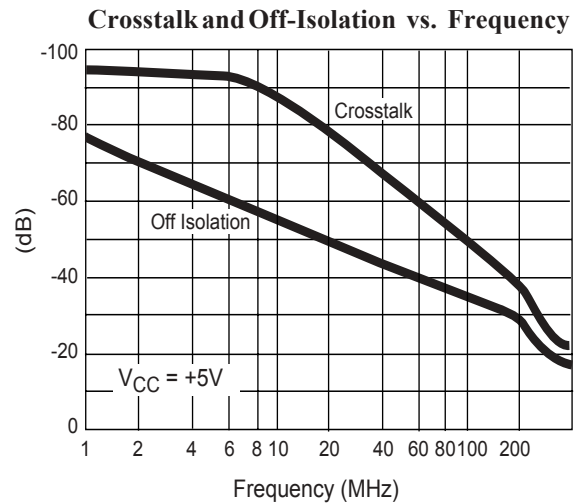
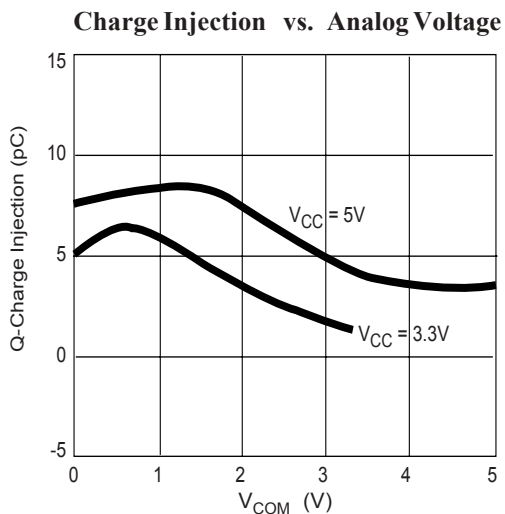
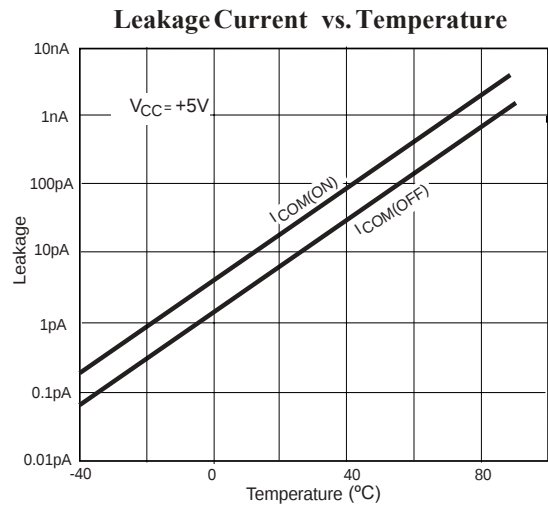
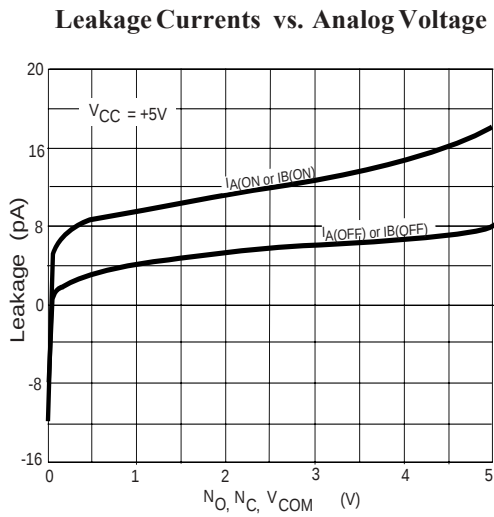
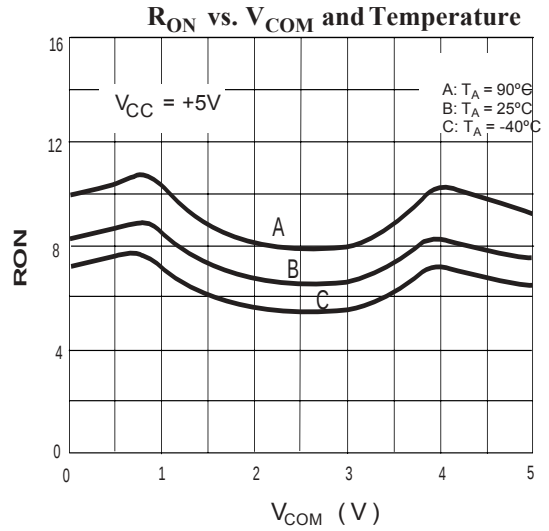
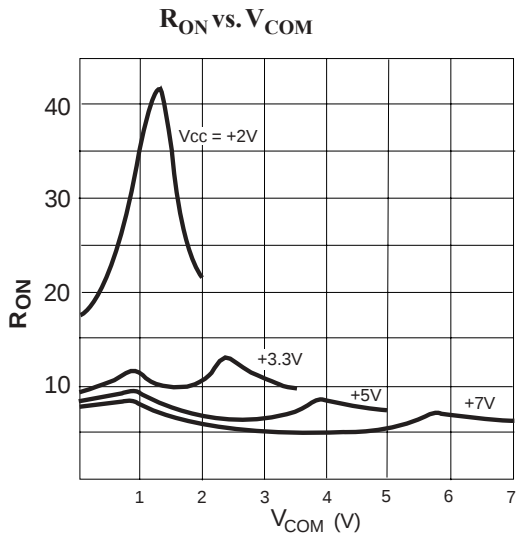
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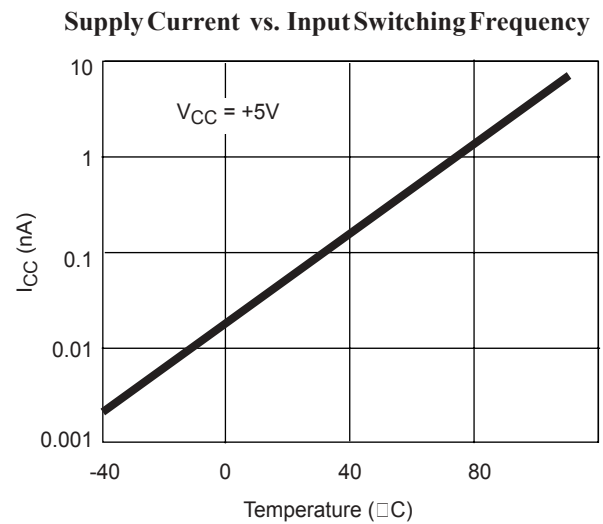
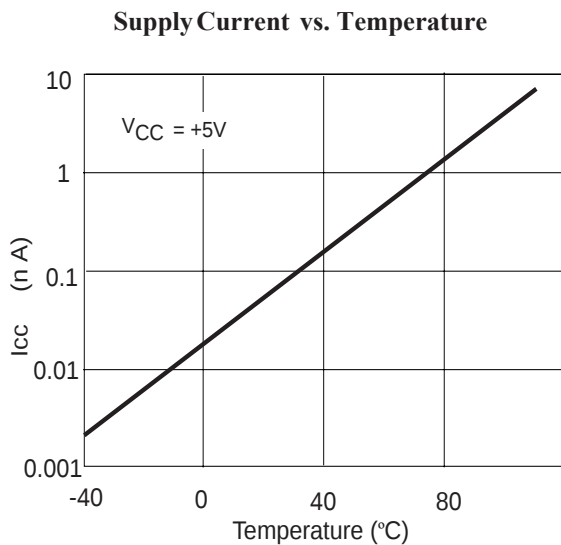
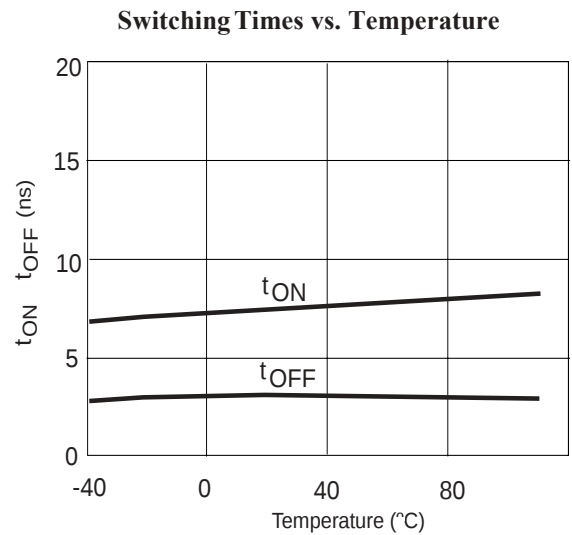
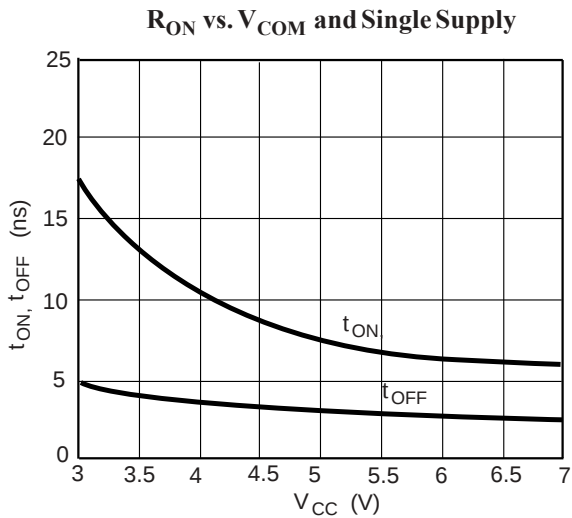
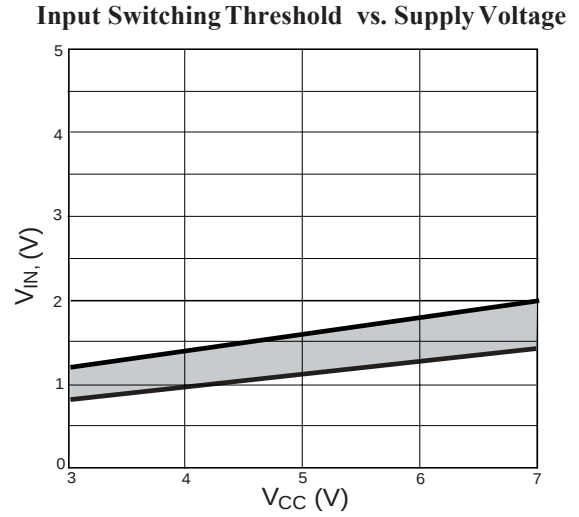
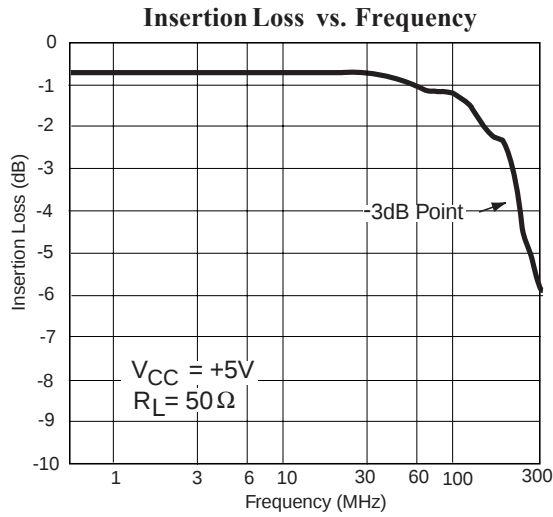
- The algebraic convention, where the most negative value is a minimum and the most positive is a maximum, is used in this data sheet.
- Typical values are for DESIGN AID ONLY, not guaranteed or subject to production testing.
- Guaranteed by design
- $\Delta R_{ON} = R_{ON \text{ max}} - R_{ON \text{ min}}$
- Flatness is defined as the difference between the maximum and minimum value of on-resistance measured.
- Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at +25°C.
- Off Isolation = $20 \log_{10} [V_{COM} / (V_{NO} \text{ or } V_{NC})]$. See figure 3.
- Between any two switches. See figure 4.

Electrical Specifications - Single +3.3V Supply
($V_{CC} = +3.3V \pm 10\%$, $GND = 0V$, $V_{INH} = 2.4V$, $V_{INL} = 0.8V$)

Parameter	Symbol	Conditions	Temp (°C)	Min ⁽¹⁾	Typ ⁽²⁾	Max ⁽¹⁾	Units
Analog Switch							
Analog Switch Range ⁽³⁾				0		V _{CC}	V
On-Resistance	R _{ON}	V _{CC} = 3V, I _{COM} = -30mA, V _{NO} or V _{NC} = 1.5V	25		12	18	
On-ResistanceMatch Between Channels ⁽⁴⁾	ΔR _{ON}		Full				
			25		5		
On-ResistanceFlatness ⁽³⁾	R _{FLATION}		Full				
		25		2	4		
		Full			5		
Dynamic							
Turn-On-Time	t _{ON}	V _{CC} = 3.3V, I _{COM} = -30mA, V _{NO} or V _{NC} =0.8V, 2.5V	25		14	25	ns
			Full			40	
Turn-On-Time	t _{OFF}		25		4.5	12	
			Full			20	
Charge Injection ⁽³⁾	Q	C _L = 1nF, V _{GEN} = 0V, R _{GEN} =0V, Figure 2	25		5	10	pC
Supply							
Positive Supply Current	I _{CC}	V _{CC} = 3.6V, V _{IN} = 0V or V _{CC} , all channels on or off	Full			1	μA

Typical Operating Characteristics ($T_A = +25^\circ\text{C}$, unless otherwise noted)





Test Circuits/Timing Diagrams

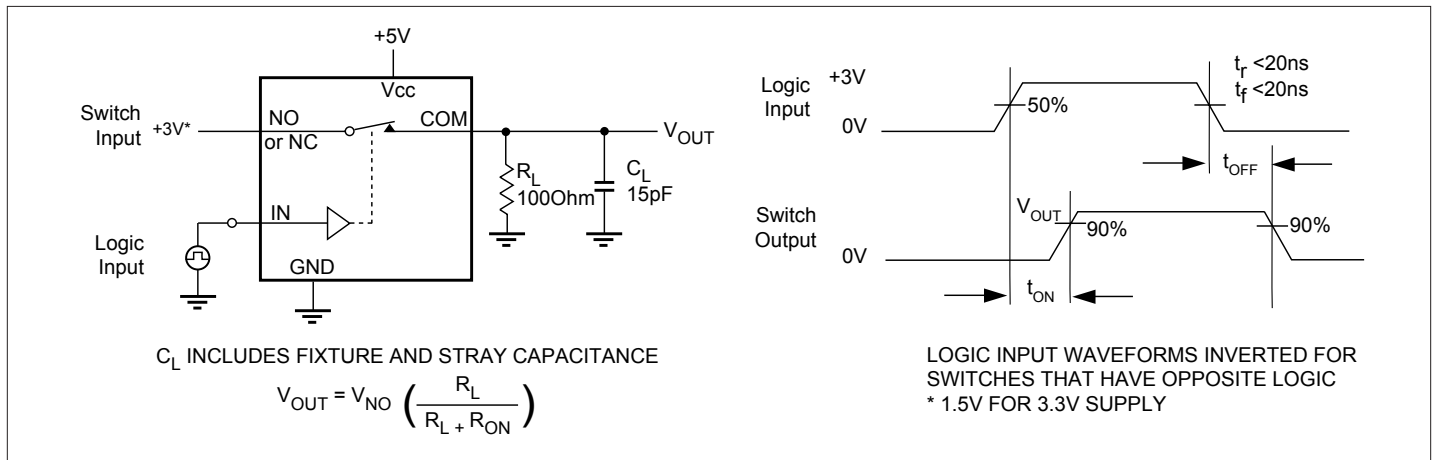


Figure 1. Switching Time

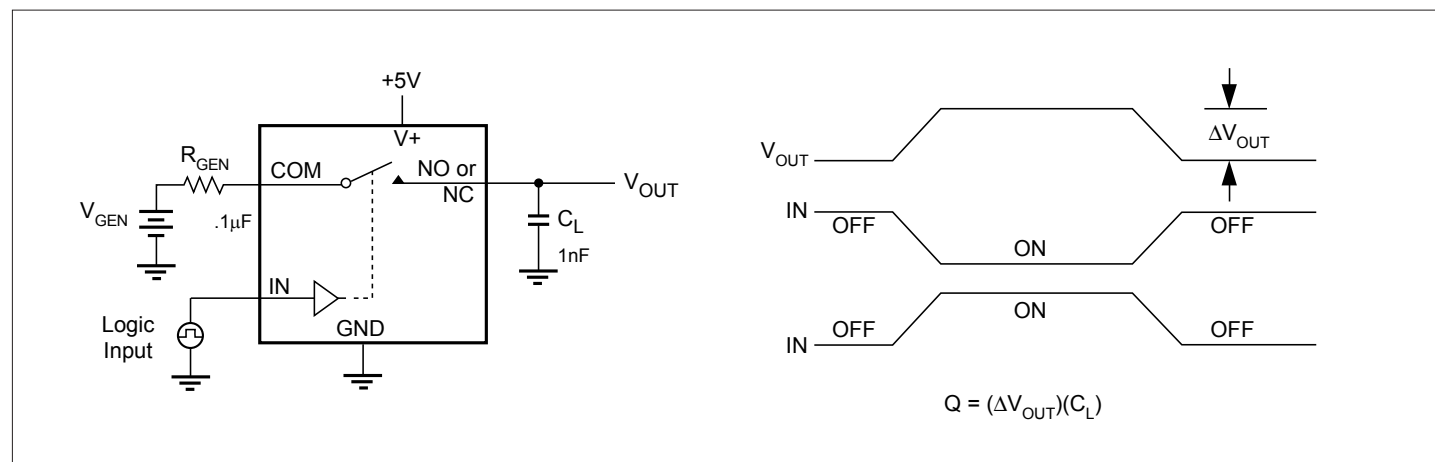


Figure 2. Charge Injection

Test Circuits/Timing Diagrams (continued)

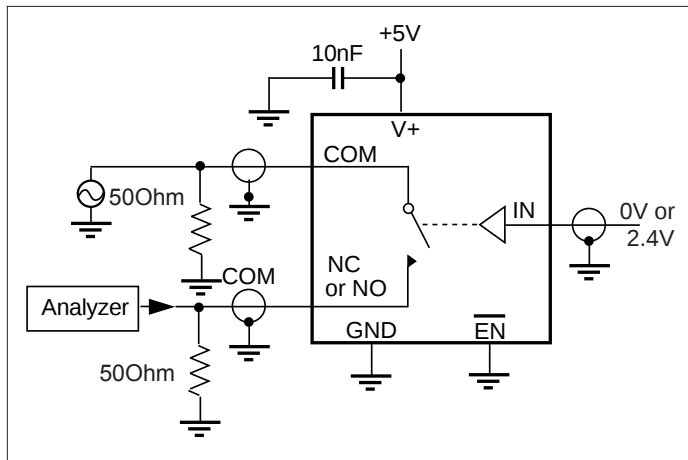


Figure 3. Off Isolation

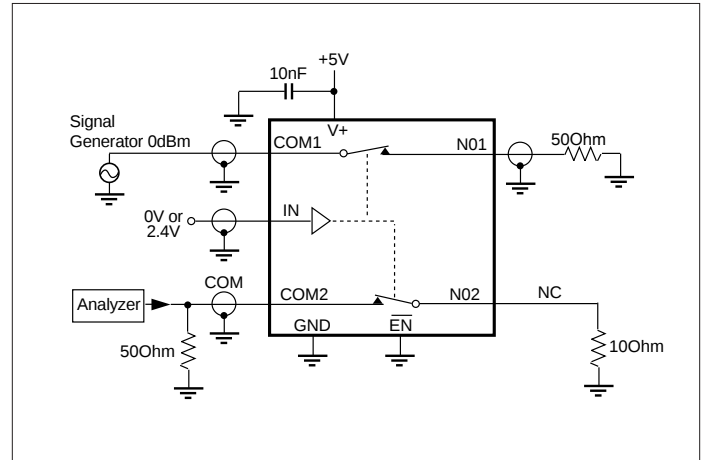


Figure 4. Crosstalk

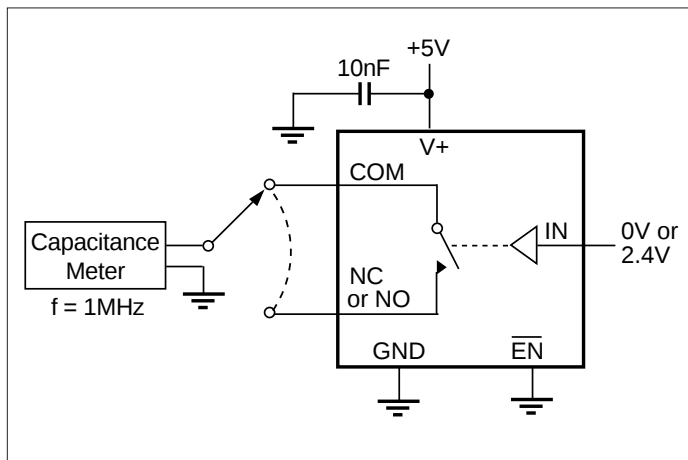


Figure 5. Channel-Off Capacitance

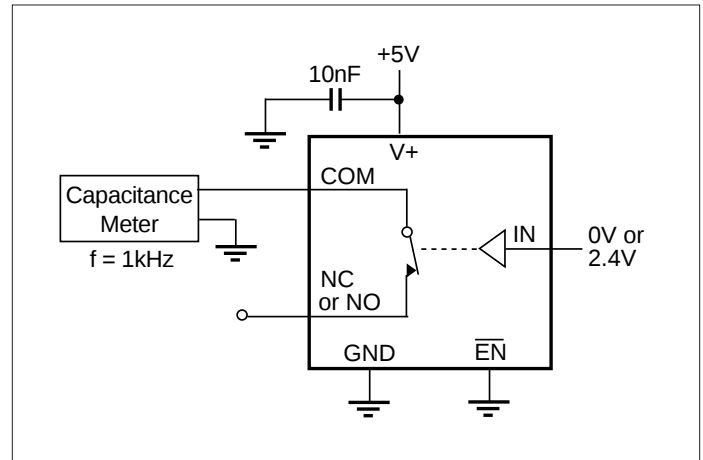


Figure 6. Channel-On Capacitance

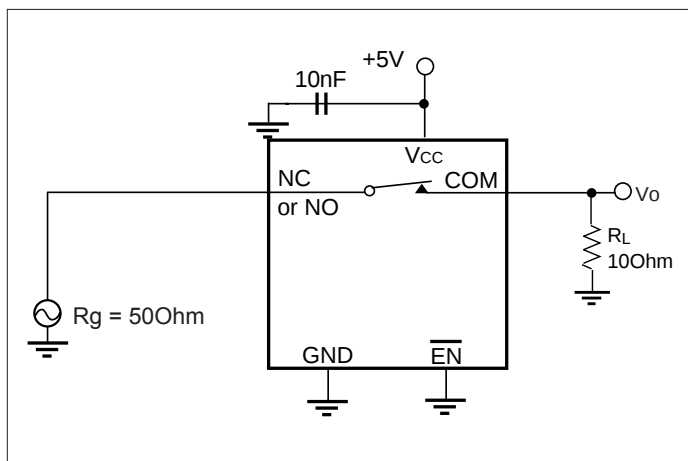


Figure 7. Bandwidth

Applications Information

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, followed by V-, and then logic inputs. If power-supply sequencing is not possible, add two small signal diodes or two current limiting resistors in series with the supply pins for overvoltage protection (Figure 8). Adding diodes reduces the analog signal range, but low switch resistance and low leakage characteristics are unaffected.

RGB Switch

Figure 9 illustrates a simple low cost RGB switch. The RGB -to-Composite Decoder produces either NTSC or S-VHS video from an RGB source. A single PI5A100 selects one of the two video sources to produce either SVHS, Composite or RGB video outputs. The low insertion loss of the PI5A100 eliminates the need for expensive input/output buffers.

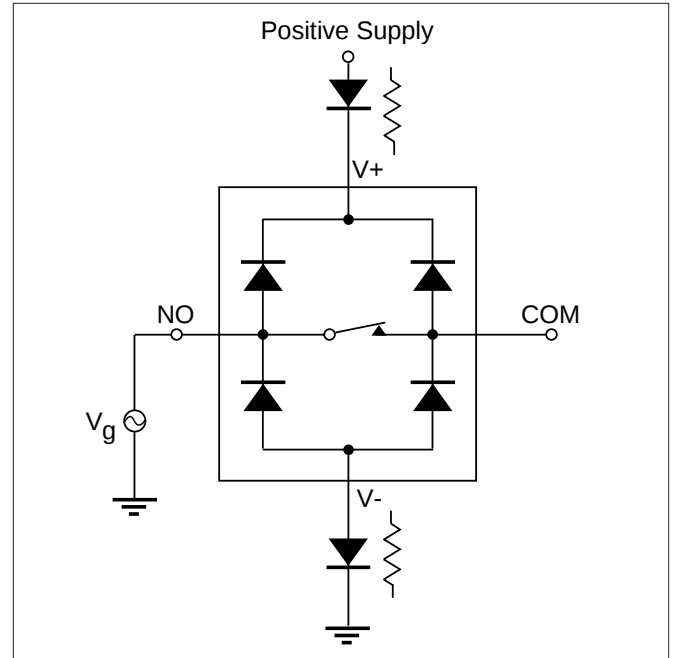


Figure 8. Overvoltage protection is accomplished using two external blocking diodes or two current limiting resistors.

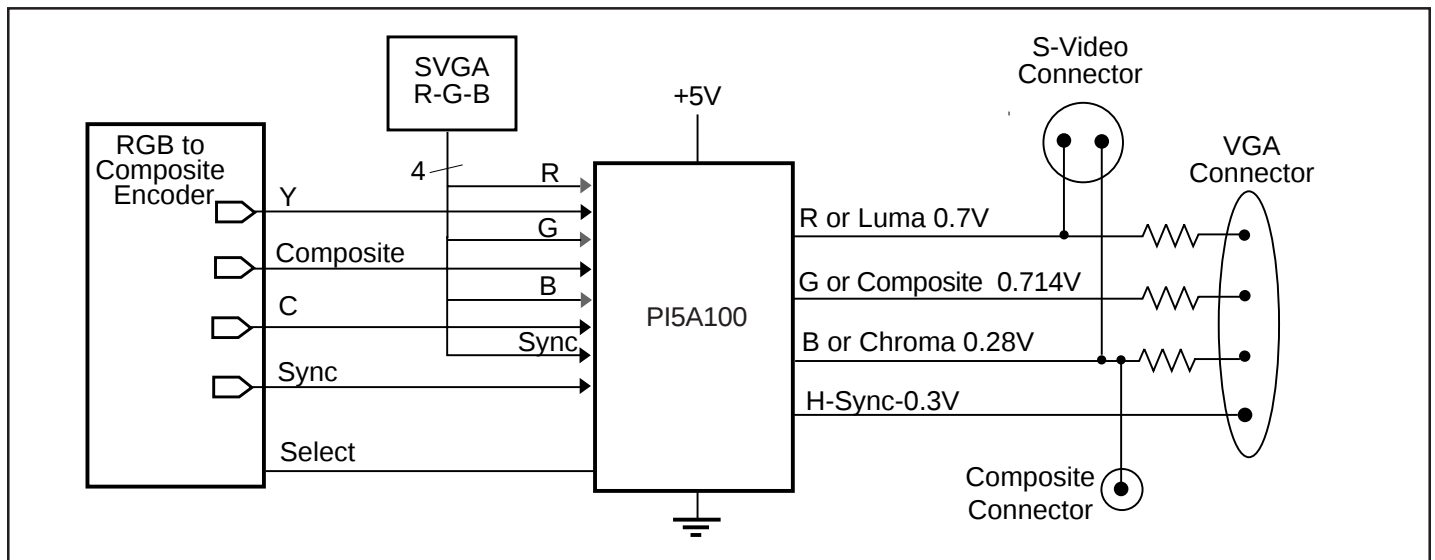


Figure 9 The single PI5A100 is used to select SVHS, VGA or Composite video outputs.

Applications

Audio Muting Function

Figure 8 shows the PI5A100 in an audio card muting application. The original problem was one of excessive popping/clicking noise appearing when connecting/disconnecting external loads, and at power on/off. The PI5A100 performs a muting function by grounding the outputs at power on/off and during the transition time. The 32Ω headset impedance demands a very low and very flat switch-on resistance to reduce THD and signal loss.

Paralleling two sections of the PI5A100 produces a Ron of 2.5Ω with an unsurpassed $\pm 0.5\Omega$ flatness.

To handle AC signals it was necessary to power the device with $\pm 3V$ provided by two Zener diodes: Z1 and Z2. The select and Enable control signals are shifted by using two 2.5V Zener diodes Z3, Z4 and pull down resistors connected to -3V.

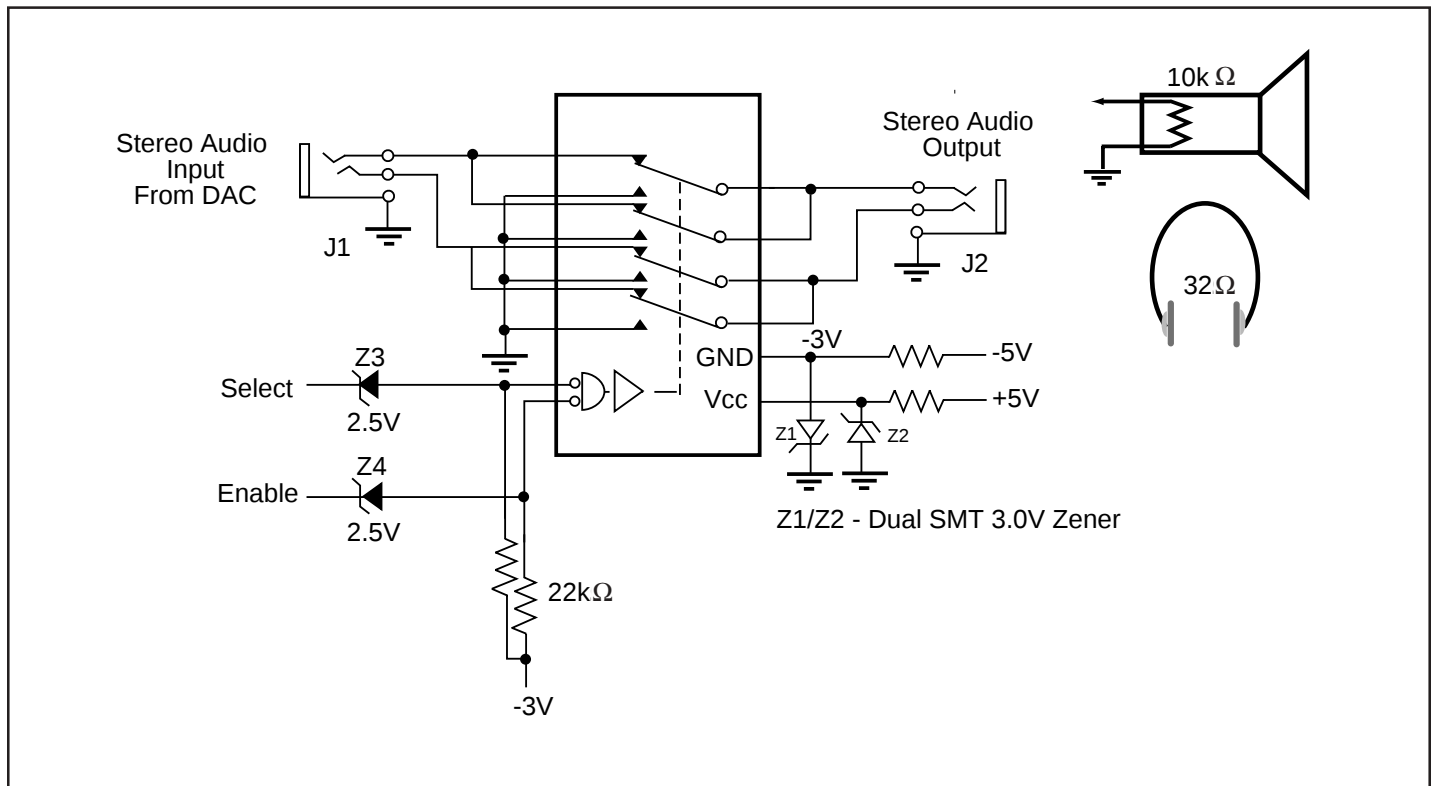
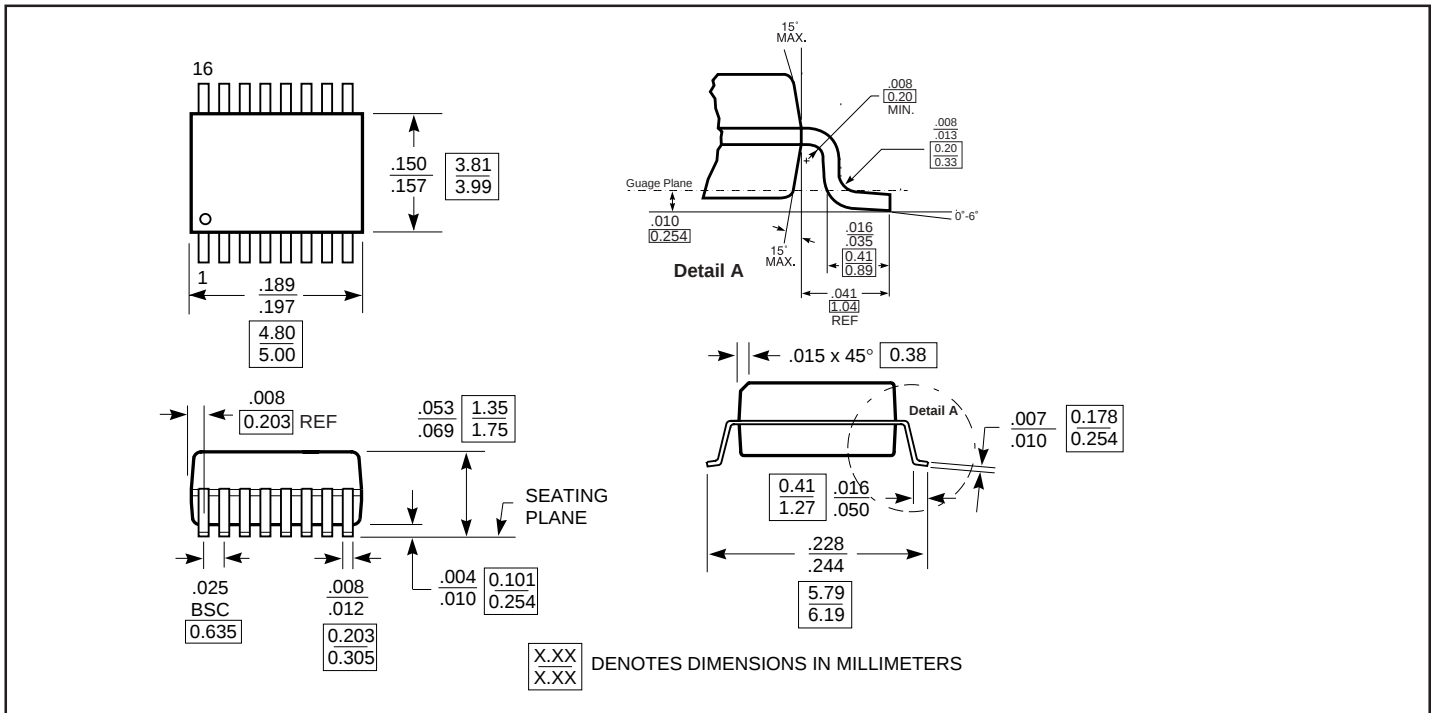
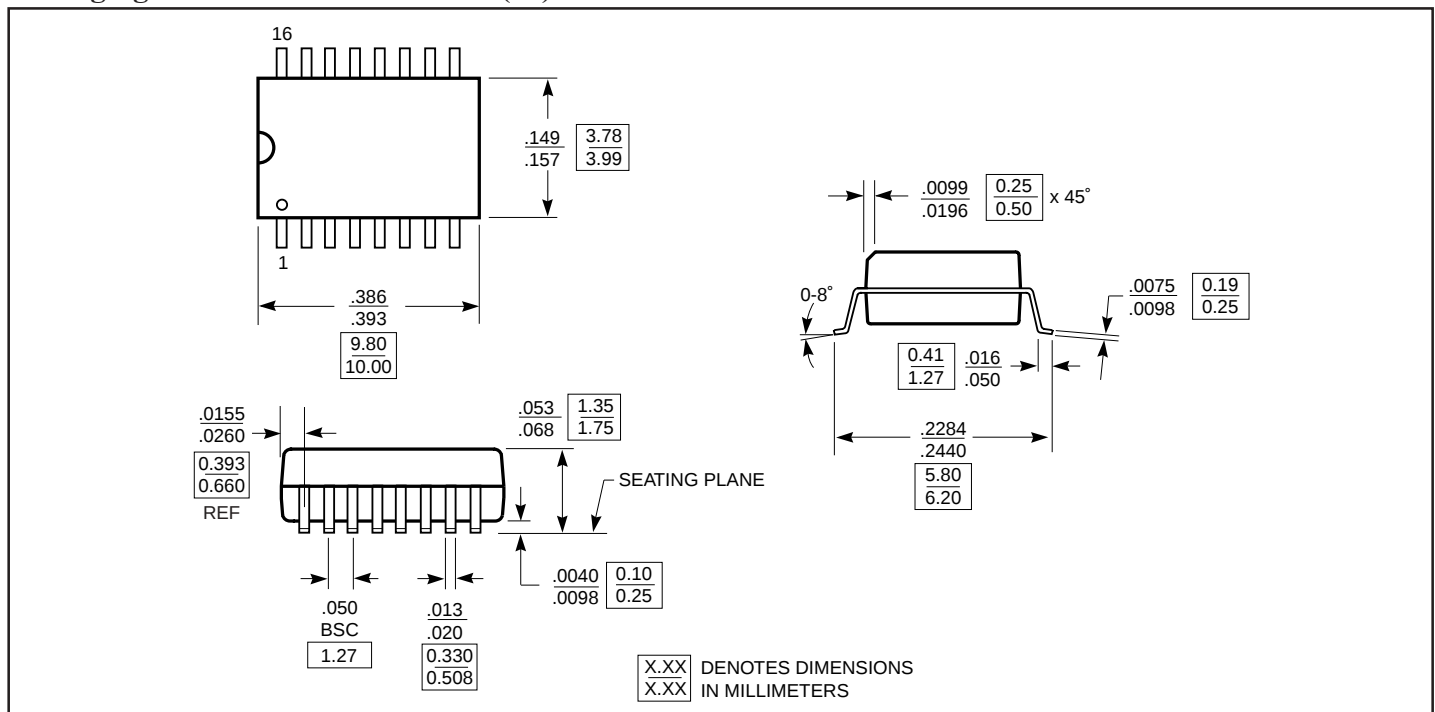


Figure 10. The PI5A100 momentarily mutes the stereo outputs by connecting them to ground during transition times.

Packaging Mechanical: 16-Pin QSOP (Q)



Packaging Mechanical: 16-Pin SOIC (W)



Ordering Information

Part Number	Package Information
PI5A100W	16-pin SOIC
PI5A100Q	16-pin QSOP

Pericom Semiconductor Corporation

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